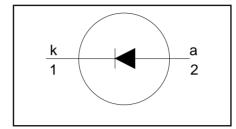
# PBYR1045 series

# **FEATURES**

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

# **SYMBOL**



# QUICK REFERENCE DATA

$$V_R = 40 \text{ V} / 45 \text{ V}$$
 $I_{F(AV)} = 10 \text{ A}$ 
 $V_F \le 0.57 \text{ V}$ 

#### **GENERAL DESCRIPTION**

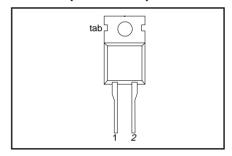
Schottky rectifier diodes in a plastic envelope. Intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYR1045 series is supplied in the conventional leaded SOD59 (TO220AC) package.

# **PINNING**

PIN	DESCRIPTION		
1	cathode		
2	anode		
tab	cathode		

# SOD59 (TO220AC)



# **LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER CONDITIONS		MIN.	MAX.		UNIT
		PBYR10		40	45	
$V_{RRM}$	Peak repetitive reverse voltage		-	40	45	V
$V_{RWM}$	Working peak reverse voltage		-	40	45	V
$V_R$	Continuous reverse voltage	T <sub>mb</sub> ≤ 113 °C	-	40	45	V
I <sub>F(AV)</sub>	Average rectified forward current	square wave; $\delta = 0.5$ ; $T_{mb} \le 136$ °C	-	10		A
I <sub>FRM</sub>	Repetitive peak forward current	square wave; $\delta = 0.5$ ; $T_{mb} \le 136$ °C	-	2	0	Α
I <sub>FSM</sub>	Non-repetitive peak forward current	t = 10  ms t = 8.3  ms sinusoidal; $T_j = 125 ^{\circ}\text{C}$ prior to surge; with reapplied $V_{\text{RRM(max)}}$	- -		35 50	A A
I <sub>RRM</sub>	Peak repetitive reverse surge current	pulse width and repetition rate limited by T <sub>i max</sub>	-	•	1	Α
T <sub>j</sub>	Operating junction temperature	Jillax	-	15	50	°C
$T_{stg}$	Storage temperature		- 65	17	75	°C

# THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub>	Thermal resistance junction		-	-	2	K/W
R <sub>th i-a</sub>	to mounting base Thermal resistance junction to ambient	in free air	-	60	-	K/W

PBYR1045 series

# **ELECTRICAL CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise specified

·) =						
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{F}$	Forward voltage	I <sub>F</sub> = 10 A; T <sub>j</sub> = 125°C I <sub>F</sub> = 20 A; T <sub>j</sub> = 125°C	-	0.5	0.57	V
·		$I_{\rm F} = 20 \text{ A}; T_{\rm i} = 125 ^{\circ}\text{C}$	-	0.69	0.72	V
		$I_{\rm F} = 20  {\rm A}^{-1}$	-	0.65	0.84	V
I <sub>R</sub>	Reverse current	$\dot{V}_R = V_{RWM}$	-	0.2	1.3	mΑ
'`		$V_{R} = V_{RWM}$ ; $T_{i} = 100^{\circ}C$	-	22	35	mA
C <sub>d</sub>	Junction capacitance	$V_{R} = 5 \text{ V}; \text{ f} = 1 \text{ MHz}, T_{i} = 25 ^{\circ}\text{C} \text{ to } 125 ^{\circ}\text{C}$	-	350	-	pF

# PBYR1045 series

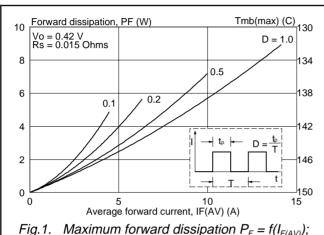


Fig.1. Maximum forward dissipation  $P_F = f(I_{F(AV)})$ ; square current waveform where  $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$ .

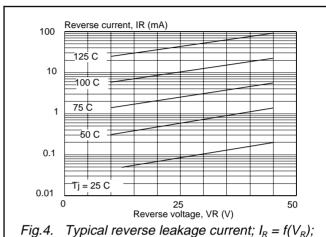


Fig.4. Typical reverse leakage current;  $I_R = f(V_R)$ ; parameter  $T_j$ 

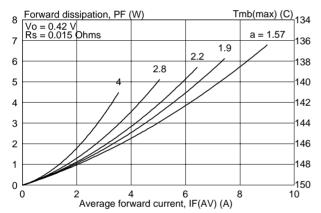


Fig.2. Maximum forward dissipation  $P_F = f(I_{F(AV)})$ ; sinusoidal current waveform where a = form factor  $= I_{F(RMS)} / I_{F(AV)}$ .

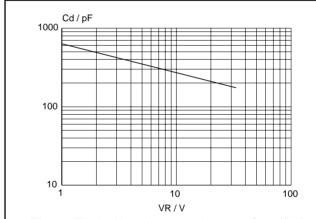


Fig.5. Typical junction capacitance;  $C_d = f(V_R)$ ; f = 1 MHz;  $T_j = 25^{\circ}$ C to 125  $^{\circ}$ C.

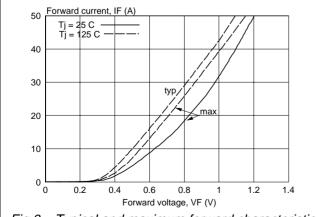
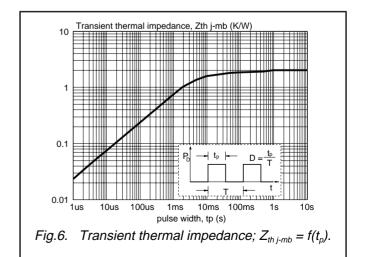
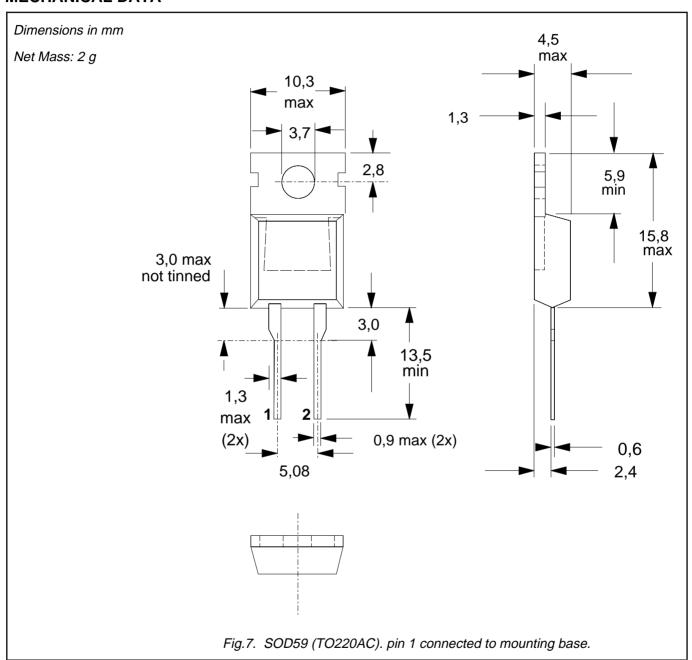


Fig.3. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$ 



PBYR1045 series

# **MECHANICAL DATA**



- Refer to mounting instructions for TO220 envelopes.
   Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

# Rectifier diodes PBYR1045 series Schottky barrier

#### **DEFINITIONS**

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limiting values					

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

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